FEB 2 4 2006



HAMRE, SCHUMANN, MUELLER & LARSON, P.C.

AN INTERNATIONAL INTELLECTUAL PROPERTY LAW FIRM

FAX TRANSMISSION

February 24, 2006

TO:

Mail Stop: AF

Examiner: NGUYEN

Commissioner for Patents

PO Box 1450

Alexandria, VA 22313-1450

FROM: Douglas P. Mueller

OUR REF: 12844.15USD1

TELEPHONE: (612) 455.3800

Total pages, including cover letter:

PTO FAX NUMBER: 571,273.8300

If all pages are NOT received, please call us at 612.455.3800 or fax us at 612.455.3801.

Title of Document:

AMENDMENT UNDER 37 C.F.R. §1.116

Applicant:

FUJIMORI

Serial No.:

10/825033

App. Filed:

April 14, 2004

Group Art No.: 2812

Please charge any additional fees or credit overpayment to Deposit Account No. 50-3478. Please consider this a PETITION FOR EXTENSION OF TIME for a sufficient number of months to enter these papers, if appropriate.

Name: Douglas P. Mueller

Reg. No. 30,300

I hereby certify that this paper is being transmitted by facsimile to the U.S. Patent and Trademark Office on the date shown below.

Lisa A. Dorn

Signature

February 24, 2006

Date

RECEIVED CENTRAL FAX CENTER

FEB 2 4 2006

S/N 10/825033

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

FUJIMORI

Examiner:

Nguyen

Serial No.:

10/825033

Group Art Unit:

2812

Filed:

April 14, 2004

Docket No.:

12844.0015USD1

Title:

METHOD OF MANUFACTURING FERROELECTRIC SUBSTANCE

THIN FILM AND FERROELECTRIC MEMORY USING THE

FERROELECTRIC SUBSTANCE THIN FILM

CERTIFICATE UNDER 37 CFR 1.6(d):

I hereby certify that this paper is being transmitted by facsimile to the U.S. Patent and Trademark Office on February 24.

2006.

By: Name: Lisa A. Dom

Mail Stop AF Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

AMENDMENT UNDER 37 C.F.R. §1.116

Dear Sir:

In response to the final Office Action mailed November 25, 2005 for the above-identified patent application, Applicant respectfully requests entry and consideration of the following amendment and remarks.

Amendments to the Claims are reflected in the listing of claims that begins on page 2 of this paper.

Remarks begin on page 4 of this paper.